

Features

- High Voltage Type (20V Rating)
- Cascadable in Multiples of 4 Bits
- Set to "15" Input and "15" Detect Output
- 100% Tested for Quiescent Current at 20V
- 5V, 10V and 15V Parametric Ratings
- Standardized Symmetrical Output Characteristics
- Maximum Input Current of 1 μ A at 18V Over Full Package Temperature Range; 100nA at 18V and +25°C
- Noise Margin (Over Full Package/Temperature Range)
 - 1V at VDD = 5V
 - 2V at VDD = 10V
 - 2.5V at VDD = 15V
- Meets All Requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

Applications

- Numerical Control
- Instrumentation
- Digital Filtering
- Frequency Synthesis

Description

CD4089BMS is a low power 4 bit digital rate multiplier that provides an output pulse rate that is the clock-input-pulse rate multiplied by $\frac{1}{16}$ times the binary input. For example, when the binary input number is 13, there will be 13 output pulses for every 16 input pulses. This device may be used in

conjunction with an up/down counter and control logic used to perform arithmetic operations (adds, subtract, divide, raise to a power), solve algebraic and differential equations, generate natural logarithms and trigometric functions, A/D and D/A conversions, and frequency division.

For words of more than 4 bits, CD4089BMS devices may be cascaded in two different modes: an Add mode and a Multiply mode (see Figures 3 and 4). In the Add mode some of the gaps left by the more significant unit at the count of 15 are filled in by the less significant units. For example, when two units are cascaded in the Add mode and programmed to 11 and 13, respectively, the more significant unit will have 11 output pulses for every 16 input pulses and the other unit will have 13 output pulses for every 256 input pulses for a total of

$$\frac{11}{16} + \frac{13}{256} = \frac{189}{256}$$

In the Multiply mode the fraction programmed into the first rate multiplier is multiplied by the fraction programmed into the second multiplier. Thus the output rate will be

$$\frac{11}{16} \times \frac{13}{16} = \frac{143}{256}$$

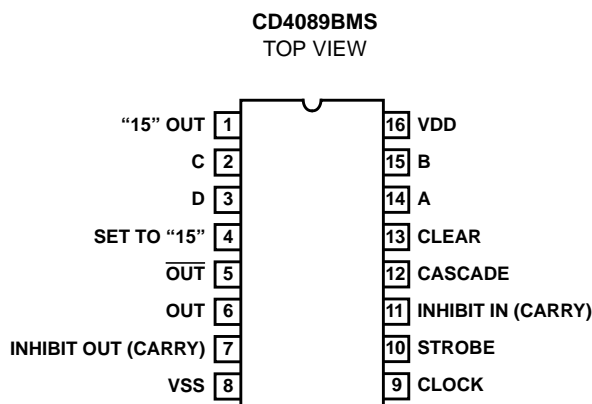
The CD4089BMS has an internal synchronous 4 bit counter which, together with one of the four binary input bits, produces pulse trains as shown in Figure 6.

If more than one binary input bit is high, the resulting pulse train is a combination of the separate pulse trains as shown in Figure 6.

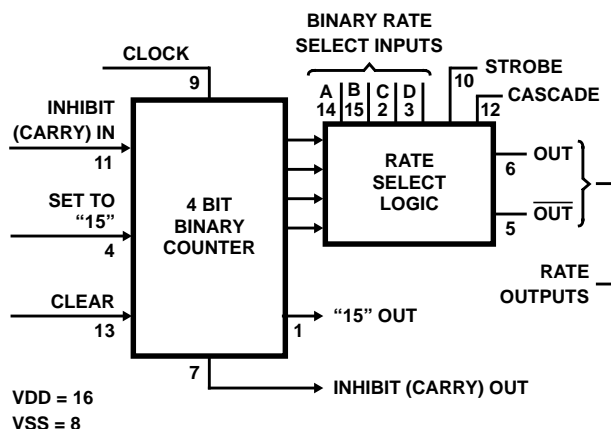
The CD4089BMS is supplied in these 16-lead outline packages:

| | |
|------------------|-----|
| Braze Seal DIP | H4W |
| Frit Seal DIP | H2R |
| Ceramic Flatpack | H6P |

Pinout



Functional Diagram



Specifications CD4089BMS

Absolute Maximum Ratings

DC Supply Voltage Range, (VDD) -0.5V to +20V
 (Voltage Referenced to VSS Terminals)
 Input Voltage Range, All Inputs -0.5V to VDD +0.5V
 DC Input Current, Any One Input $\pm 10\text{mA}$
 Operating Temperature Range -55°C to +125°C
 Package Types D, F, K, H
 Storage Temperature Range (TSTG) -65°C to +150°C
 Lead Temperature (During Soldering) +265°C
 At Distance 1/16 \pm 1/32 Inch (1.59mm \pm 0.79mm) from case for
 10s Maximum

Reliability Information

Thermal Resistance θ_{ja} θ_{jc}
 Ceramic DIP and FRIT Package 80°C/W 20°C/W
 Flatpack Package 70°C/W 20°C/W
 Maximum Package Power Dissipation (PD) at +125°C
 For TA = -55°C to +100°C (Package Type D, F, K) 500mW
 For TA = +100°C to +125°C (Package Type D, F, K) Derate
 Linearity at 12mW/°C to 200mW
 Device Dissipation per Output Transistor 100mW
 For TA = Full Package Temperature Range (All Package Types)
 Junction Temperature +175°C

TABLE 1. DC ELECTRICAL PERFORMANCE CHARACTERISTICS

| PARAMETER | SYMBOL | CONDITIONS (NOTE 1) | | GROUP A SUBGROUPS | TEMPERATURE | LIMITS | | UNITS |
|--------------------------------|--------|---------------------------------------|-----------|----------------------|----------------------|----------------|----------------|---------------|
| | | | | | | MIN | MAX | |
| Supply Current | IDD | VDD = 20V, VIN = VDD or GND | | 1 | +25°C | - | 10 | μA |
| | | | | 2 | +125°C | - | 1000 | μA |
| | | VDD = 18V, VIN = VDD or GND | | 3 | -55°C | - | 10 | μA |
| Input Leakage Current | IIL | VIN = VDD or GND | VDD = 20 | 1 | +25°C | -100 | - | nA |
| | | | | 2 | +125°C | -1000 | - | nA |
| | | | VDD = 18V | 3 | -55°C | -100 | - | nA |
| Input Leakage Current | IIH | VIN = VDD or GND | VDD = 20 | 1 | +25°C | - | 100 | nA |
| | | | | 2 | +125°C | - | 1000 | nA |
| | | | VDD = 18V | 3 | -55°C | - | 100 | nA |
| Output Voltage | VOL15 | VDD = 15V, No Load | | 1, 2, 3 | +25°C, +125°C, -55°C | - | 50 | mV |
| Output Voltage | VOH15 | VDD = 15V, No Load (Note 3) | | 1, 2, 3 | +25°C, +125°C, -55°C | 14.95 | - | V |
| Output Current (Sink) | IOL5 | VDD = 5V, VOUT = 0.4V | | 1 | +25°C | 0.53 | - | mA |
| Output Current (Sink) | IOL10 | VDD = 10V, VOUT = 0.5V | | 1 | +25°C | 1.4 | - | mA |
| Output Current (Sink) | IOL15 | VDD = 15V, VOUT = 1.5V | | 1 | +25°C | 3.5 | - | mA |
| Output Current (Source) | IOH5A | VDD = 5V, VOUT = 4.6V | | 1 | +25°C | - | -0.53 | mA |
| Output Current (Source) | IOH5B | VDD = 5V, VOUT = 2.5V | | 1 | +25°C | - | -1.8 | mA |
| Output Current (Source) | IOH10 | VDD = 10V, VOUT = 9.5V | | 1 | +25°C | - | -1.4 | mA |
| Output Current (Source) | IOH15 | VDD = 15V, VOUT = 13.5V | | 1 | +25°C | - | -3.5 | mA |
| N Threshold Voltage | VNTH | VDD = 10V, ISS = -10 μA | | 1 | +25°C | -2.8 | -0.7 | V |
| P Threshold Voltage | VPTH | VSS = 0V, IDD = 10 μA | | 1 | +25°C | 0.7 | 2.8 | V |
| Functional | F | VDD = 2.8V, VIN = VDD or GND | | 7 | +25°C | VOH > VDD/2 | VOL < VDD/2 | V |
| | | VDD = 20V, VIN = VDD or GND | | 7 | +25°C | | | |
| | | VDD = 18V, VIN = VDD or GND | | 8A | +125°C | | | |
| | | VDD = 3V, VIN = VDD or GND | | 8B | -55°C | | | |
| Input Voltage Low (Note 2) | VIL | VDD = 5V, VOH > 4.5V, VOL < 0.5V | | 1, 2, 3 | +25°C, +125°C, -55°C | - | 1.5 | V |
| Input Voltage High (Note 2) | VIH | VDD = 5V, VOH > 4.5V, VOL < 0.5V | | 1, 2, 3 | +25°C, +125°C, -55°C | 3.5 | - | V |
| Input Voltage Low (Note 2) | VIL | VDD = 15V, VOH > 13.5V, VOL < 1.5V | | 1, 2, 3 | +25°C, +125°C, -55°C | - | 4 | V |
| Input Voltage High (Note 2) | VIH | VDD = 15V, VOH > 13.5V, VOL < 1.5V | | 1, 2, 3 | +25°C, +125°C, -55°C | 11 | - | V |

NOTES: 1. All voltages referenced to device GND, 100% testing being implemented.
 2. Go/No Go test with limits applied to inputs.
 3. For accuracy, voltage is measured differentially to VDD. Limit is 0.050V max.

Specifications CD4089BMS

TABLE 2. AC ELECTRICAL PERFORMANCE CHARACTERISTICS

| PARAMETER | SYMBOL | CONDITIONS (NOTES 1, 2) | GROUP A SUBGROUPS | TEMPERATURE | LIMITS | | UNITS |
|--------------------------------------|----------------|----------------------------|----------------------|---------------|--------|------|-------|
| | | | | | MIN | MAX | |
| Propagation Delay Clock to Output | TPHL1 TPLH1 | VDD = 5V, VIN = VDD or GND | 9 | +25°C | - | 300 | ns |
| | | | 10, 11 | +125°C, -55°C | - | 405 | ns |
| Propagation Delay Clear to Out | TPHL2 TPLH2 | VDD = 5V, VIN = VDD or GND | 9 | +25°C | - | 760 | ns |
| | | | 10, 11 | +125°C, -55°C | - | 1026 | ns |
| Propagation Delay Cascade to Out | TPHL3 TPLH3 | VDD = 5V, VIN = VDD or GND | 9 | +25°C | - | 180 | ns |
| | | | 10, 11 | +125°C, -55°C | - | 243 | ns |
| Transition Time | TTHL TTLH | VDD = 5V, VIN = VDD or GND | 9 | +25°C | - | 200 | ns |
| | | | 10, 11 | +125°C, -55°C | - | 270 | ns |
| Maximum Clock Input Frequency | FCL | VDD = 5V, VIN = VDD or GND | 9 | +25°C | 1.2 | - | MHz |
| | | | 10, 11 | +125°C, -55°C | .89 | - | MHz |

NOTES:

1. CL = 50pF, RL = 200K, Input TR, TF < 20ns.
2. -55°C and +125°C limits guaranteed, 100% testing being implemented.

TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS

| PARAMETER | SYMBOL | CONDITIONS | NOTES | TEMPERATURE | LIMITS | | UNITS |
|-------------------------|--------|-----------------------------|-------|-------------------------|--------|-------|-------|
| | | | | | MIN | MAX | |
| Supply Current | IDD | VDD = 5V, VIN = VDD or GND | 1, 2 | -55°C, +25°C | - | 5 | μA |
| | | | | +125°C | - | 150 | μA |
| | | VDD = 10V, VIN = VDD or GND | 1, 2 | -55°C, +25°C | - | 10 | μA |
| | | | | +125°C | - | 300 | μA |
| | | VDD = 15V, VIN = VDD or GND | 1, 2 | -55°C, +25°C | - | 10 | μA |
| | | | | +125°C | - | 600 | μA |
| Output Voltage | VOL5 | VDD = 5V, No Load | 1, 2 | +25°C, +125°C, -55°C | - | 50 | mV |
| Output Voltage | VOL10 | VDD = 10V, No Load | 1, 2 | +25°C, +125°C, -55°C | - | 50 | mV |
| Output Voltage | VOH5 | VDD = 5V, No Load | 1, 2 | +25°C, +125°C, -55°C | 4.95 | - | V |
| Output Voltage | VOH10 | VDD = 10V, No Load | 1, 2 | +25°C, +125°C, -55°C | 9.95 | - | V |
| Output Current (Sink) | IOL5 | VDD = 5V, VOUT = 0.4V | 1, 2 | +125°C | 0.36 | - | mA |
| | | | | -55°C | 0.64 | - | mA |
| Output Current (Sink) | IOL10 | VDD = 10V, VOUT = 0.5V | 1, 2 | +125°C | 0.9 | - | mA |
| | | | | -55°C | 1.6 | - | mA |
| Output Current (Sink) | IOL15 | VDD = 15V, VOUT = 1.5V | 1, 2 | +125°C | 2.4 | - | mA |
| | | | | -55°C | 4.2 | - | mA |
| Output Current (Source) | IOH5A | VDD = 5V, VOUT = 4.6V | 1, 2 | +125°C | - | -0.36 | mA |
| | | | | -55°C | - | -0.64 | mA |
| Output Current (Source) | IOH5B | VDD = 5V, VOUT = 2.5V | 1, 2 | +125°C | - | -1.15 | mA |
| | | | | -55°C | - | -2.0 | mA |
| Output Current (Source) | IOH10 | VDD = 10V, VOUT = 9.5V | 1, 2 | +125°C | - | -0.9 | mA |
| | | | | -55°C | - | -1.6 | mA |
| Output Current (Source) | IOH15 | VDD = 15V, VOUT = 13.5V | 1, 2 | +125°C | - | -2.4 | mA |
| | | | | -55°C | - | -4.2 | mA |

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TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS (Continued)

| PARAMETER | SYMBOL | CONDITIONS | NOTES | TEMPERATURE | LIMITS | | UNITS |
|--|----------------|-------------------------------|------------|----------------------|--------|-----|-------|
| | | | | | MIN | MAX | |
| Input Voltage Low | VIL | VDD = 10V, VOH > 9V, VOL < 1V | 1, 2 | +25°C, +125°C, -55°C | - | 3 | V |
| Input Voltage High | VIH | VDD = 10V, VOH > 9V, VOL < 1V | 1, 2 | +25°C, +125°C, -55°C | +7 | - | V |
| Propagation Delay Clock to Out | TPHL4 TPLH4 | VDD = 5V | 1, 2, 3 | +25°C | - | 220 | ns |
| | | VDD = 10V | 1, 2, 3 | +25°C | - | 110 | ns |
| | | VDD = 15V | 1, 2, 3 | +25°C | - | 90 | ns |
| Propagation Delay Clock to Out | TPHL1 TPLH1 | VDD = 10V | 1, 2, 3 | +25°C | - | 150 | ns |
| | | VDD = 15V | 1, 2, 3 | +25°C | - | 120 | ns |
| Propagation Delay Clock to Inhibit Out | TPHL5 | VDD = 5V | 1, 2, 3 | +25°C | - | 720 | ns |
| | | VDD = 10V | 1, 2, 3 | +25°C | - | 320 | ns |
| | | VDD = 15V | 1, 2, 3 | +25°C | - | 220 | ns |
| Propagation Delay Clock to Inhibit Out | TPLH5 | VDD = 5V | 1, 2, 3 | +25°C | - | 500 | ns |
| | | VDD = 10V | 1, 2, 3 | +25°C | - | 200 | ns |
| | | VDD = 15V | 1, 2, 3 | +25°C | - | 150 | ns |
| Propagation Delay Clear to Out | TPHL2 TPLH2 | VDD = 10V | 1, 2, 3 | +25°C | - | 350 | ns |
| | | VDD = 15V | 1, 2, 3 | +25°C | - | 260 | ns |
| Propagation Delay Cascade to Out | TPHL3 TPLH3 | VDD = 10V | 1, 2, 3 | +25°C | - | 90 | ns |
| | | VDD = 15V | 1, 2, 3 | +25°C | - | 70 | ns |
| Propagation Delay Clock to "9" or "15" Out | TPHL6 TPLH6 | VDD = 5V | 1, 2, 3 | +25°C | - | 600 | ns |
| | | VDD = 10V | 1, 2, 3 | +25°C | - | 250 | ns |
| | | VDD = 15V | 1, 2, 3 | +25°C | - | 180 | ns |
| Propagation Delay Inhibit In to Inhibit Out | TPHL7 TPLH7 | VDD = 5V | 1, 2, 3 | +25°C | - | 320 | ns |
| | | VDD = 10V | 1, 2, 3 | +25°C | - | 150 | ns |
| | | VDD = 15V | 1, 2, 3 | +25°C | - | 110 | ns |
| Propagation Delay Set to Out | TPHL8 TPLH8 | VDD = 5V | 1, 2, 3 | +25°C | - | 660 | ns |
| | | VDD = 10V | 1, 2, 3 | +25°C | - | 300 | ns |
| | | VDD = 15V | 1, 2, 3 | +25°C | - | 220 | ns |
| Transition Time | TTHL TTLH | VDD = 10V | 1, 2, 3 | +25°C | - | 100 | ns |
| | | VDD = 15V | 1, 2, 3 | +25°C | - | 80 | ns |
| Maximum Clock Input Frequency | FCL | VDD = 10V | 1, 2, 3 | +25°C | 2.5 | - | MHz |
| | | VDD = 15V | 1, 2, 3 | +25°C | 3.5 | - | MHz |
| Minimum Inhibit-In Setup Time | TSU | VDD = 5V | 1, 2, 3 | +25°C | - | 100 | ns |
| | | VDD = 10V | 1, 2, 3 | +25°C | - | 40 | ns |
| | | VDD = 15V | 1, 2, 3 | +25°C | - | 20 | ns |
| Minimum Inhibit-In Removal Time | TREM | VDD = 5V | 1, 2, 3 | +25°C | - | 240 | ns |
| | | VDD = 10V | 1, 2, 3 | +25°C | - | 130 | ns |
| | | VDD = 15V | 1, 2, 3 | +25°C | - | 110 | ns |
| Minimum Clock Pulse Width | TW | VDD = 5V | 1, 2, 3 | +25°C | - | 330 | ns |
| | | VDD = 10V | 1, 2, 3 | +25°C | - | 170 | ns |
| | | VDD = 15V | 1, 2, 3 | +25°C | - | 100 | ns |
| Maximum Clock Rise and Fall Time | TRCL TFCL | VDD = 5V | 1, 2, 3, 4 | +25°C | - | 15 | μs |
| | | VDD = 10V | 1, 2, 3, 4 | +25°C | - | 15 | μs |
| | | VDD = 15V | 1, 2, 3, 4 | +25°C | - | 15 | μs |

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TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS (Continued)

| PARAMETER | SYMBOL | CONDITIONS | NOTES | TEMPERATURE | LIMITS | | UNITS |
|----------------------------------|--------|------------|---------|-------------|--------|-----|-------|
| | | | | | MIN | MAX | |
| Minimum Set Removal Time | TREM | VDD = 5V | 1, 2, 3 | +25°C | - | 150 | ns |
| | | VDD = 10V | 1, 2, 3 | +25°C | - | 80 | ns |
| | | VDD = 15V | 1, 2, 3 | +25°C | - | 50 | ns |
| Minimum Clear Removal Time | TREM | VDD = 5V | 1, 2, 3 | +25°C | - | 60 | ns |
| | | VDD = 10V | 1, 2, 3 | +25°C | - | 40 | ns |
| | | VDD = 15V | 1, 2, 3 | +25°C | - | 30 | ns |
| Minimum Set or Clear Pulse Width | TW | VDD = 5V | 1, 2, 3 | +25°C | - | 160 | ns |
| | | VDD = 10V | 1, 2, 3 | +25°C | - | 90 | ns |
| | | VDD = 15V | 1, 2, 3 | +25°C | - | 60 | ns |
| Input Capacitance | CIN | Any Input | 1, 2 | +25°C | - | 7.5 | pF |

NOTES:

1. All voltages referenced to device GND.
2. The parameters listed on Table 3 are controlled via design or process and are not directly tested. These parameters are characterized on initial design release and upon design changes which would affect these characteristics.
3. CL = 50pF, RL = 200K, Input TR, TF < 20ns.
4. If more than one unit is cascaded, TRCL should be made less than or equal to the sum of the transition time and the fixed propagation delay of the output of the driving stage for the estimated capacitive load.

TABLE 4. POST IRRADIATION ELECTRICAL PERFORMANCE CHARACTERISTICS

| PARAMETER | SYMBOL | CONDITIONS | NOTES | TEMPERATURE | LIMITS | | UNITS |
|---------------------------|--------------|-----------------------------|------------|-------------|-------------|--------------------|-------|
| | | | | | MIN | MAX | |
| Supply Current | IDD | VDD = 20V, VIN = VDD or GND | 1, 4 | +25°C | - | 25 | μA |
| N Threshold Voltage | VNTH | VDD = 10V, ISS = -10μA | 1, 4 | +25°C | -2.8 | -0.2 | V |
| N Threshold Voltage Delta | ΔVTN | VDD = 10V, ISS = -10μA | 1, 4 | +25°C | - | ±1 | V |
| P Threshold Voltage | VTP | VSS = 0V, IDD = 10μA | 1, 4 | +25°C | 0.2 | 2.8 | V |
| P Threshold Voltage Delta | ΔVTP | VSS = 0V, IDD = 10μA | 1, 4 | +25°C | - | ±1 | V |
| Functional | F | VDD = 18V, VIN = VDD or GND | 1 | +25°C | VOH > VDD/2 | VOL < VDD/2 | V |
| | | VDD = 3V, VIN = VDD or GND | | | | | |
| Propagation Delay Time | TPHL TPLH | VDD = 5V | 1, 2, 3, 4 | +25°C | - | 1.35 x +25°C Limit | ns |

- NOTES: 1. All voltages referenced to device GND. 3. See Table 2 for +25°C limit.
2. CL = 50pF, RL = 200K, Input TR, TF < 20ns. 4. Read and Record

TABLE 5. BURN-IN AND LIFE TEST DELTA PARAMETERS +25°C

| PARAMETER | SYMBOL | DELTA LIMIT |
|-------------------------|--------|--------------------------|
| Supply Current - MSI-2 | IDD | ± 1.0μA |
| Output Current (Sink) | IOL5 | ± 20% x Pre-Test Reading |
| Output Current (Source) | IOH5A | ± 20% x Pre-Test Reading |

TABLE 6. APPLICABLE SUBGROUPS

| CONFORMANCE GROUP | MIL-STD-883 METHOD | GROUP A SUBGROUPS | READ AND RECORD |
|----------------------------|--------------------|-------------------|------------------|
| Initial Test (Pre Burn-In) | 100% 5004 | 1, 7, 9 | IDD, IOL5, IOH5A |

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TABLE 6. APPLICABLE SUBGROUPS

| CONFORMANCE GROUP | | MIL-STD-883 METHOD | GROUP A SUBGROUPS | READ AND RECORD |
|-------------------------------|--------------|--------------------|---------------------------------------|------------------------------|
| Interim Test 1 (Post Burn-In) | | 100% 5004 | 1, 7, 9 | IDD, IOL5, IOH5A |
| Interim Test 2 (Post Burn-In) | | 100% 5004 | 1, 7, 9 | IDD, IOL5, IOH5A |
| PDA (Note 1) | | 100% 5004 | 1, 7, 9, Deltas | |
| Interim Test 3 (Post Burn-In) | | 100% 5004 | 1, 7, 9 | IDD, IOL5, IOH5A |
| PDA (Note 1) | | 100% 5004 | 1, 7, 9, Deltas | |
| Final Test | | 100% 5004 | 2, 3, 8A, 8B, 10, 11 | |
| Group A | | Sample 5005 | 1, 2, 3, 7, 8A, 8B, 9, 10, 11 | |
| Group B | Subgroup B-5 | Sample 5005 | 1, 2, 3, 7, 8A, 8B, 9, 10, 11, Deltas | Subgroups 1, 2, 3, 9, 10, 11 |
| | Subgroup B-6 | Sample 5005 | 1, 7, 9 | |
| Group D | | Sample 5005 | 1, 2, 3, 8A, 8B, 9 | Subgroups 1, 2 3 |

NOTE: 1. 5% Parametric, 3% Functional; Cumulative for Static 1 and 2.

TABLE 7. TOTAL DOSE IRRADIATION

| CONFORMANCE GROUPS | MIL-STD-883 METHOD | TEST | | READ AND RECORD | |
|--------------------|--------------------|-----------|------------|-----------------|------------|
| | | PRE-IRRAD | POST-IRRAD | PRE-IRRAD | POST-IRRAD |
| Group E Subgroup 2 | 5005 | 1, 7, 9 | Table 4 | 1, 9 | Table 4 |

TABLE 8. BURN-IN AND IRRADIATION TEST CONNECTIONS

| FUNCTION | OPEN | GROUND | VDD | 9V ± -0.5V | OSCILLATOR | |
|---------------------------|--------|--------------------|-----------|------------|------------|-------|
| | | | | | 50kHz | 25kHz |
| Static Burn-In 1 (Note 1) | 1, 5-7 | 2-4, 8-15 | 16 | | | |
| Static Burn-In 2 (Note 1) | 1, 5-7 | 8 | 2-4, 9-16 | | | |
| Dynamic Burn-In (Note 1) | - | 2, 4, 8, 10, 12-15 | 3, 16 | 1, 5-7 | 9 | 11 |
| Irradiation (Note 2) | 1, 5-7 | 8 | 2-4, 9-16 | | | |

NOTES:

- Each pin except VDD and GND will have a series resistor of $10K \pm 5\%$, $VDD = 18V \pm 0.5V$
- Each pin except VDD and GND will have a series resistor of $47K \pm 5\%$; Group E, Subgroup 2, sample size is 4 dice/wafer, 0 failures, $VDD = 10V \pm 0.5V$

Logic Diagram

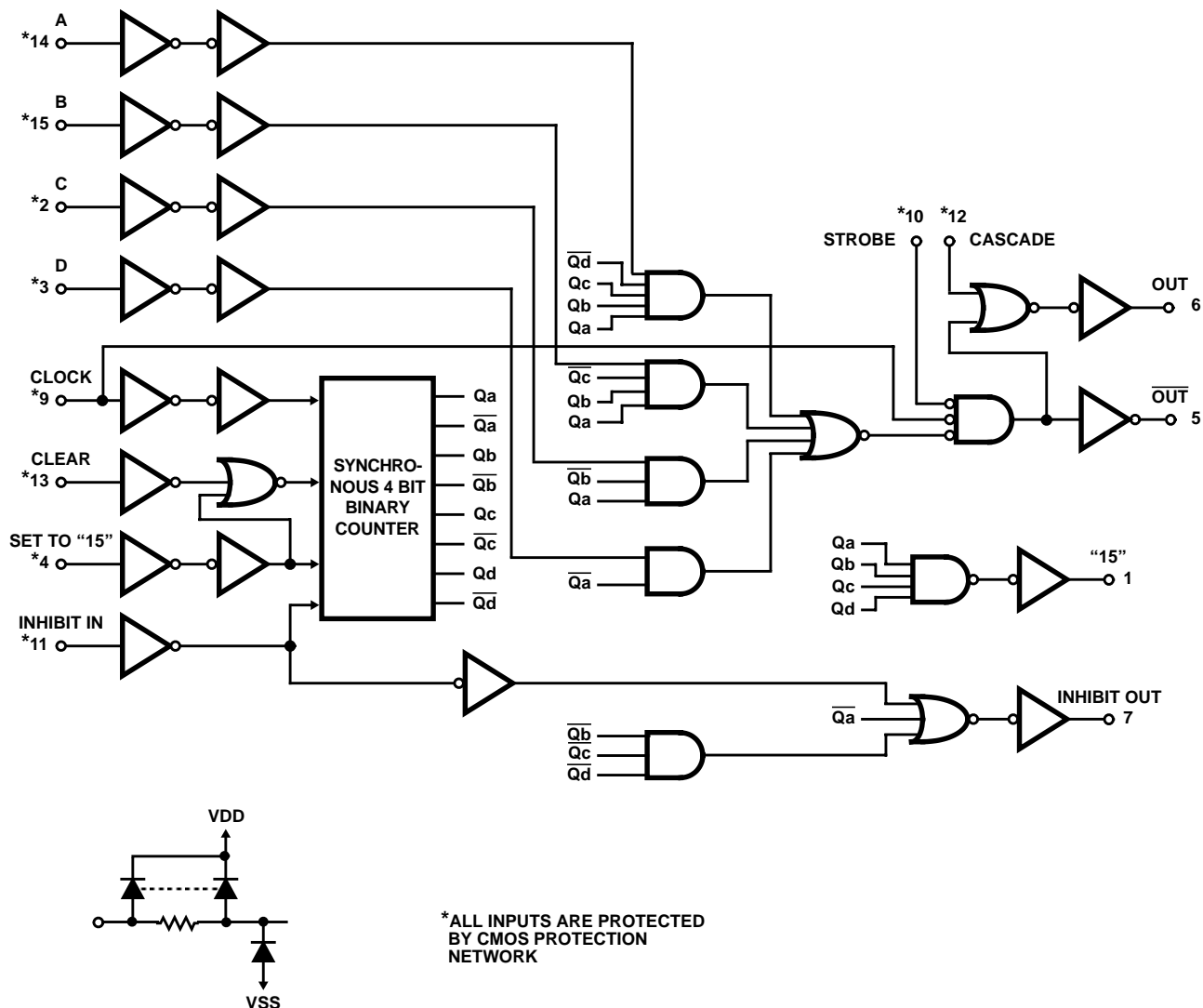


FIGURE 1. LOGIC DIAGRAM

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CD4089BMS

TRUTH TABLE

| INPUTS | | | | | | | | | | OUTPUTS | | | |
|--|---|---|---|-----|--------|-----|-----|-----|-----|---|-----|---------|----------|
| NUMBER OF PULSES OR INPUT LOGIC LEVEL (0 = Low; 1 = High; X = Don't Care) | | | | | | | | | | NUMBER OF PULSES OR OUTPUT LOGIC LEVEL (L = Low; H = High) | | | |
| D | C | B | A | CLK | INH IN | STR | CAS | CLR | SET | OUT | OUT | INH OUT | "15" OUT |
| 0 | 0 | 0 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | L | H | 1 | 1 |
| 0 | 0 | 0 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 |
| 0 | 0 | 1 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | 2 | 2 | 1 | 1 |
| 0 | 0 | 1 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 3 | 3 | 1 | 1 |
| 0 | 1 | 0 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | 4 | 4 | 1 | 1 |
| 0 | 1 | 0 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 5 | 5 | 1 | 1 |
| 0 | 1 | 1 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | 6 | 6 | 1 | 1 |
| 0 | 1 | 1 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 7 | 7 | 1 | 1 |
| 1 | 0 | 0 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | 8 | 8 | 1 | 1 |
| 1 | 0 | 0 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 9 | 9 | 1 | 1 |
| 1 | 0 | 1 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | 10 | 10 | 1 | 1 |
| 1 | 0 | 1 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 11 | 11 | 1 | 1 |
| 1 | 1 | 0 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | 12 | 12 | 1 | 1 |
| 1 | 1 | 0 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 13 | 13 | 1 | 1 |
| 1 | 1 | 1 | 0 | 16 | 0 | 0 | 0 | 0 | 0 | 14 | 14 | 1 | 1 |
| 1 | 1 | 1 | 1 | 16 | 0 | 0 | 0 | 0 | 0 | 15 | 15 | 1 | 1 |
| X | X | X | X | 16 | 1 | 0 | 0 | 0 | 0 | ** | ** | H | ** |
| X | X | X | X | 16 | 0 | 1 | 0 | 0 | 0 | L | H | 1 | 1 |
| X | X | X | X | 16 | 0 | 0 | 1 | 0 | 0 | H | * | 1 | 1 |
| 1 | X | X | X | 16 | 0 | 0 | 0 | 1 | 0 | 16 | 16 | H | L |
| 0 | X | X | X | 16 | 0 | 0 | 0 | 1 | 0 | L | H | H | L |
| X | X | X | X | 16 | 0 | 0 | 0 | X | 1 | L | H | L | H |

* Output same as the first 16 lines of this truth table (depending on values A, B, C, D)

** Depends on internal state of counter

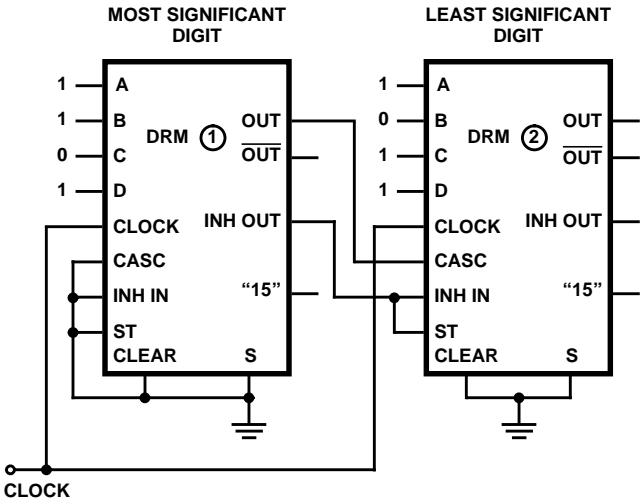


FIGURE 2. TWO CD4089BMS's CASCADED IN THE "ADD" MODE WITH A PRESET NUMBER

OF 189 $\left(\frac{11}{16} + \frac{13}{256} = \frac{189}{256}\right)$

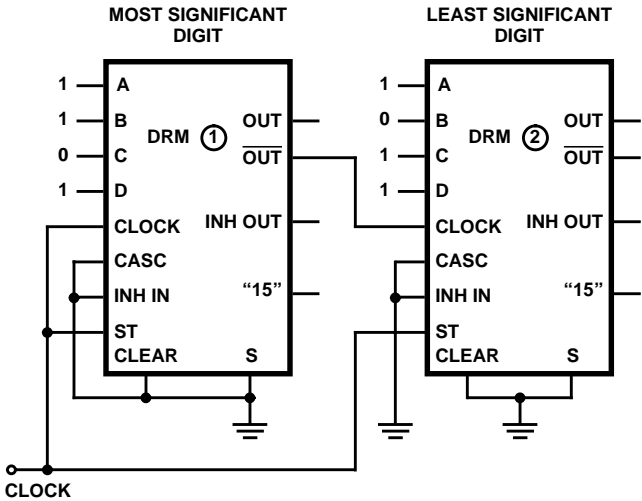


FIGURE 3. TWO CD4089BMS's CASCADED IN THE "MULTIPLY" MODE WITH A PRESET NUMBER

OF 143 $\left(\frac{11}{16} + \frac{13}{16} = \frac{143}{256}\right)$

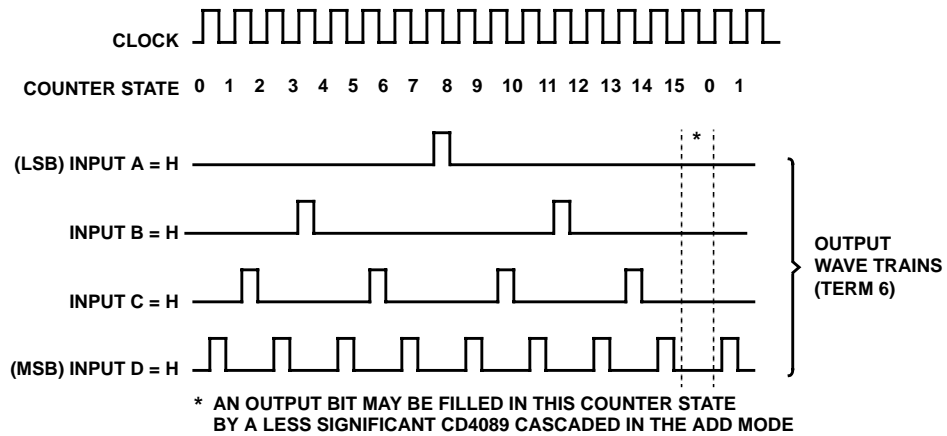


FIGURE 4. TIMING DIAGRAM

Typical Performance Characteristics

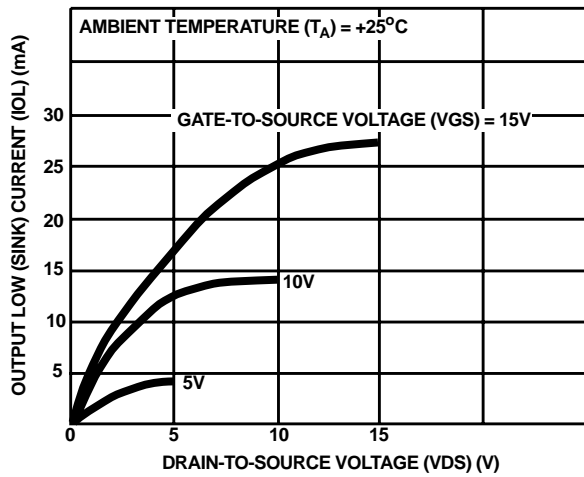


FIGURE 5. TYPICAL OUTPUT LOW (SINK) CURRENT CHARACTERISTICS

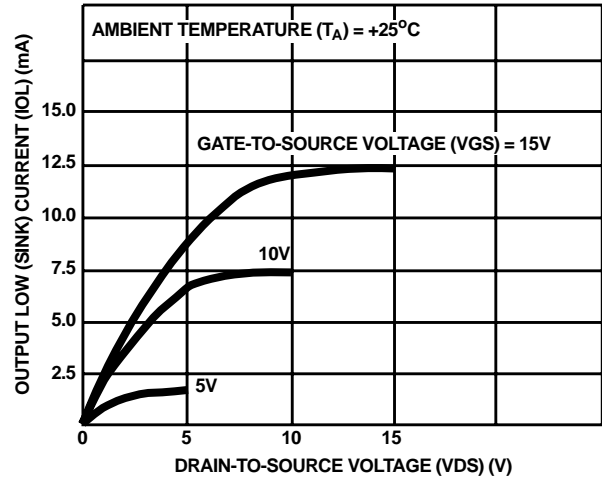


FIGURE 6. MINIMUM OUTPUT LOW (SINK) CURRENT CHARACTERISTICS

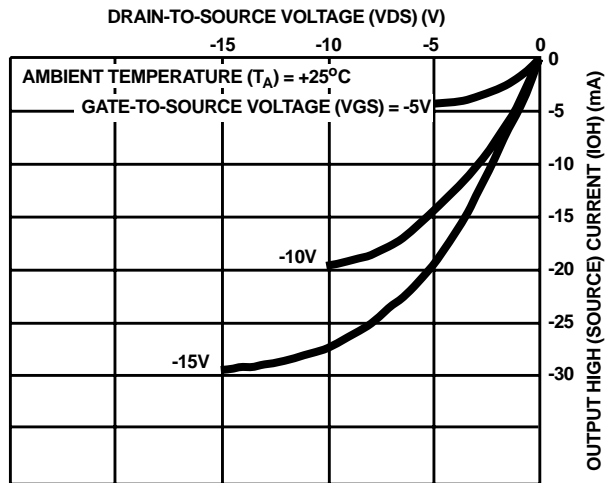


FIGURE 7. TYPICAL OUTPUT HIGH (SOURCE) CURRENT CHARACTERISTICS

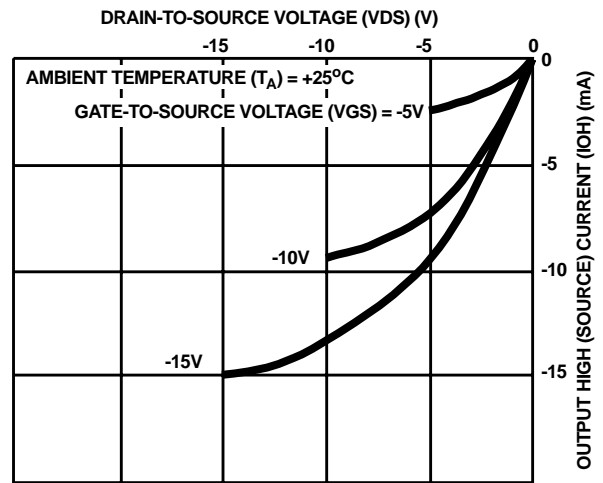


FIGURE 8. MINIMUM OUTPUT HIGH (SOURCE) CURRENT CHARACTERISTICS

Typical Performance Characteristics (Continued)

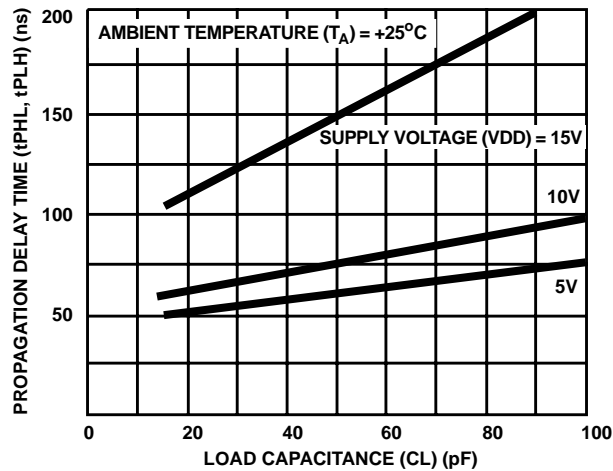


FIGURE 9. TYP. PROPAGATION DELAY TIMES AS FUNCTION OF LOAD CAPACITANCE (CLOCK OR STROBE TO OUT)

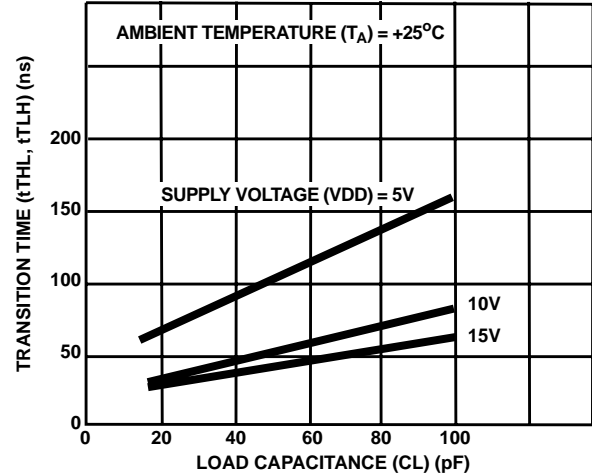


FIGURE 10. TYPICAL TRANSITION TIME AS A FUNCTION OF LOAD CAPACITANCE

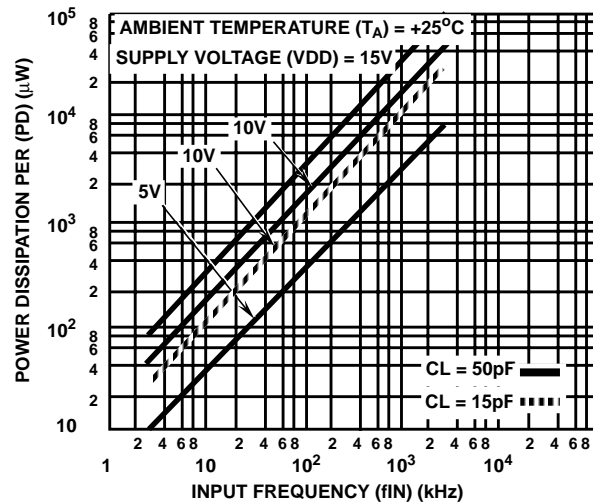
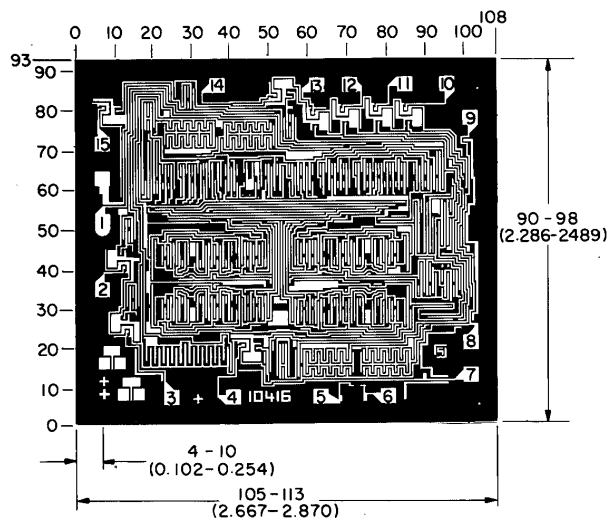


FIGURE 11. TYPICAL DYNAMIC POWER DISSIPATION AS A FUNCTION OF INPUT FREQUENCY

Chip Dimensions and Pad Layout



Dimensions in parenthesis are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

METALLIZATION: Thickness: $11\text{k}\text{\AA} - 14\text{k}\text{\AA}$, AL.

PASSIVATION: $10.4\text{k}\text{\AA} - 15.6\text{k}\text{\AA}$, Silane

BOND PADS: 0.004 inches X 0.004 inches MIN

DIE THICKNESS: 0.0198 inches - 0.0218 inches